

Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 80 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	80 A				
V_{R}	1000 V, 1200 V				
V _F at I _F	1.35 V				
I _{FSM}	1250 A				
t _{rr}	90 ns				
T _J max.	150 °C				
Package	TO-247AC 3L				
Circuit configuration	Single				
Snap factor	0.5				

FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-80APF12L-M3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	TEST CONDITIONS	TEST CONDITIONS VALUES					
V _{RRM}		1000/1200	V				
I _{F(AV)}	Sinusoidal waveform	80	Δ.				
I _{FSM}		1250	Α Α				
t _{rr}	1 A, - 100 A/μs	90	ns				
V _F	40 A, T _J = 25 °C	1.2	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-80APF10-M3	1000	1100	15				
VS-80APF12-M3	1200	1300	15				



ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T _C = 92 °C, 180° conduction half sine wave	80				
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied 1100		Α			
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	1250				
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	5000	A ² s			
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	7000	A-S			
Maximum I²√t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	70 000	A²√s			

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS VALUES UNIT				
Maximum forward voltage drop	V_{FM}	80 A, T _J = 25 °C		1.35	V	
Forward slope resistance	r _t	T _{.1} = 150 °C	4.03	mΩ		
Threshold voltage	V _{F(TO)}	1j = 150 C	0.87	V		
Maximum reverse leakage current		T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mA	
waximum reverse leakage current	I _{RM}	T _J = 150 °C	VR = nateu VRRM	15	IIIA	

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •		
Reverse recovery time	t _{rr}	I _F at 80 A _{pk}	480	ns	I _{FM} t		
Reverse recovery current	I _{rr}	25 A/µs	7.1	Α			
Reverse recovery charge	Q _{rr}	25 °C	2.1	μC	dir/ dt Q _{rr}		
Snap factor	S		0.5		I _{RM(REC)}		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and s temperature range	storage	T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resist junction to case	ance,	R _{thJC}	DC operation	0.35		
Maximum thermal resist junction to ambient	ance,	R _{thJA}		40	°C/W	
Typical thermal resistant case to heatsink	Typical thermal resistance, case to heatsink		Mounting surface, smooth, and greased	0.2		
Approximate weight				6	g	
Approximate weight				0.21	oz.	
Maunting toward	minimum			6 (5)	kgf · cm	
Mounting torque -	maximum			12 (10)	(lbf ⋅ in)	
Marking dayion	Madra da ta		Coop of the TO 247AC 21	1A08	PF10	
Marking device			Case style TO-247AC 3L	80AI	80APF12	



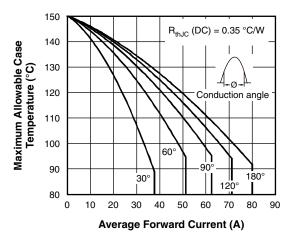


Fig. 1 - Current Rating Characteristics

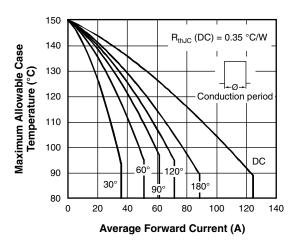


Fig. 2 - Current Rating Characteristics

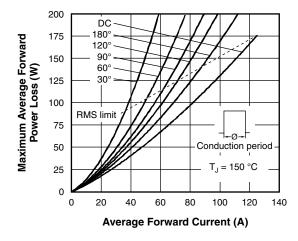


Fig. 3 - Forward Power Loss Characteristics

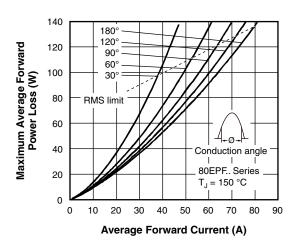


Fig. 4 - Forward Power Loss Characteristics

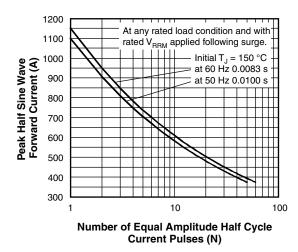


Fig. 5 - Maximum Non-Repetitive Surge Current

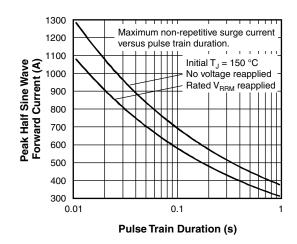


Fig. 6 - Maximum Non-Repetitive Surge Current

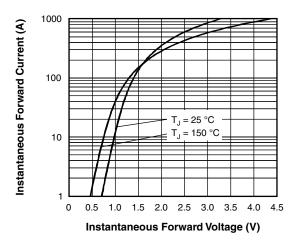


Fig. 7 - Forward Voltage Drop Characteristics

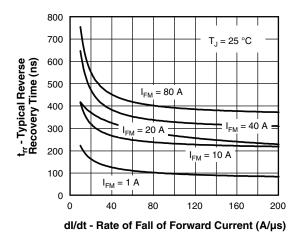


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

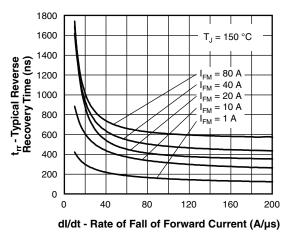


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \, ^{\circ}\text{C}$

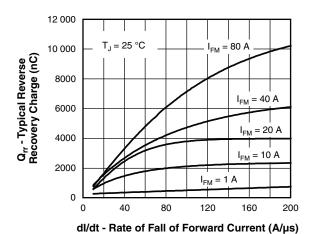


Fig. 10 - Recovery Charge Characteristics, $T_J = 25$ °C

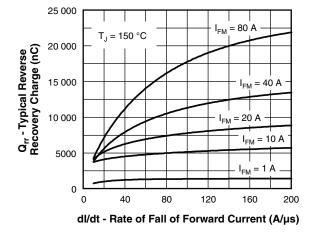


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C



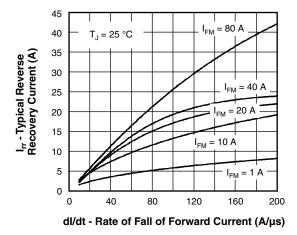
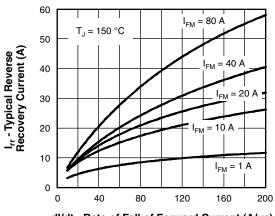


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, $T_J = 150 \, ^{\circ}\text{C}$

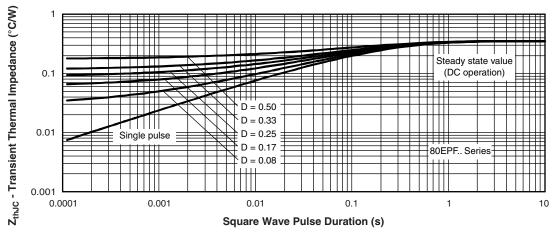


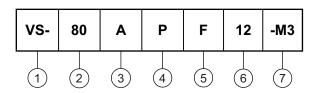
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (80 = 80 A)

- Circuit configuration:

A = single diode, 3 pins

4 - Package:

P = TO-247AC 3L

5 - Type of silicon:

F = fast recovery

6 - Voltage code x 100 = V_{RRM} - 10 = 1000 V 12 = 1200 V

7 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-80APF10-M3	25	500	Antistatic plastic tubes				
VS-80APF12-M3	25	500	Antistatic plastic tubes				

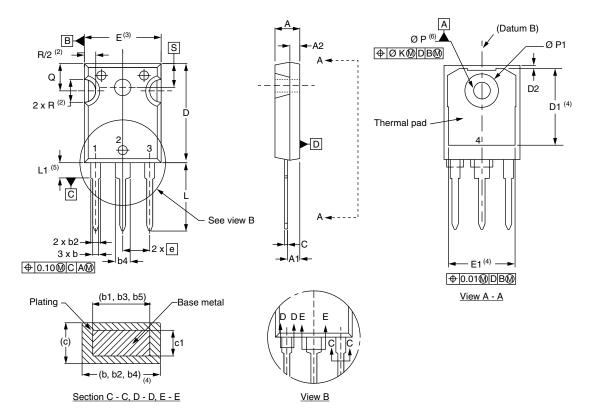
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96138				
Part marking information	www.vishay.com/doc?95007			
SPICE model	www.vishay.com/doc?96692			



Vishay Semiconductors

TO-247AC 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØΚ	0.254		0.0	0.010	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	
	•	•	•		•

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension Q



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